NSN 5961-01-297-9908

Transistor - Page 1 of 1



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Inclosure Material:

Metal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

40.0 breakdown voltage, collector-to-emitter, base open and 50.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown

voltage, emitter-to-base, collector open and 0.8 base to emitter saturation voltage

Current Rating Per Characteristic:

100.00 nanoamperes zero-gate-voltage source current preset

Special Features:

Dual amplifier

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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